TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

# HN1A01FU

Audio Frequency General Purpose Amplifier Applications

- Small package (Dual type)
- High voltage and high current

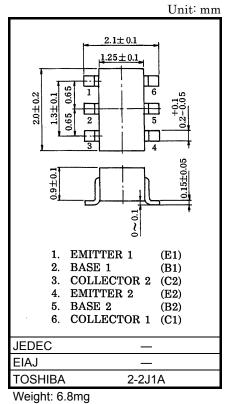
:  $V_{CEO} = -50V$ ,  $I_C = -150mA$  (max)

- High hFE: hFE = 120~400
- Excellent hFE linearity

:  $h_{FE}$  (I<sub>C</sub> =-0.1mA) /  $h_{FE}$  (I<sub>C</sub> =-2mA) = 0.95 (typ.)

#### Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	Ι <sub>C</sub>	-150	mA
Base current	Ι <sub>Β</sub>	-30	mA
Collector power dissipation	P <sub>C</sub> *	200	mW
Junction temperature	Тј	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

\* Total rating

#### Electrical Characteristics (Ta = 25°C) (Q1,Q2 Common)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	_	$V_{CB} = -50V, I_E = 0$	_	_	-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	_	$V_{EB} = -5V, I_C = 0$	_	_	-0.1	μA
DC current gain	h <sub>FE</sub> (Note)	—	$V_{CE} = -6V$ , $I_C = -2mA$	120	—	400	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA		-0.1	-0.3	V
Transition frequency	f <sub>T</sub>	_	V <sub>CE</sub> = -10V, I <sub>C</sub> = -1mA	80	_	_	MHz
Collector output capacitance	C <sub>ob</sub>	—	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f = 1MHz	_	4	7	pF

Note: hFE Classification

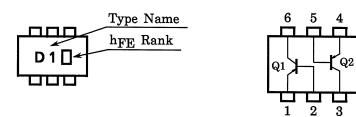
Y (Y): 120~240, GR (G): 200~400

( ) Marking Symbol



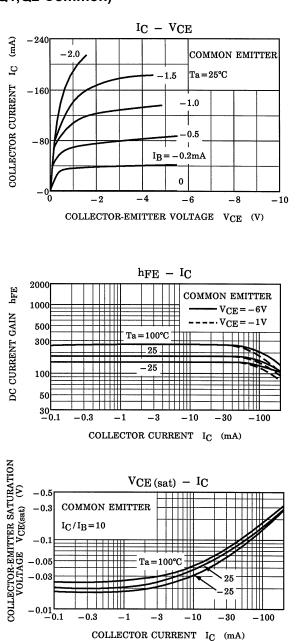
## Marking

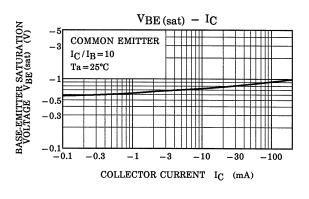
## Equivalent Circuit (Top View)

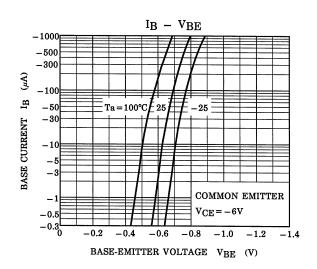


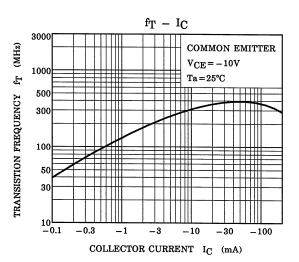
## **TOSHIBA**

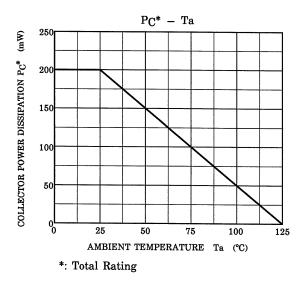
### (Q1,Q2 Common)











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20070701-EN GENERAL

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